TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MZ245FK

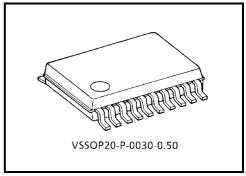
Low Voltage Octal Bus Transceiver with 5 V Tolerant Inputs and Outputs

The TC7MZ245FK is a high performance cmos octal bus transceiver. Designed for use in $3.3~\rm V$ systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage $(3.3\ V)\ VCC$ applications, but it could be used to interface to $5\ V$ supply environment for both inputs and outputs.

The direction of data transmission is determined by the level of the DIR input. The enable input (\overline{OE}) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.03 g (typ.)

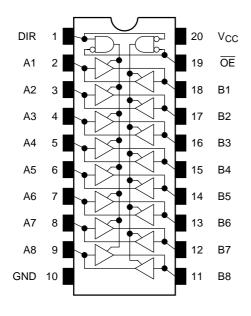
Features

- Low voltage operation: $V_{CC} = 2.0 \sim 3.6 \text{ V}$
- High speed operation: $t_{pd} = 7.0 \text{ ns (max) (VCC} = 3.0 \sim 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Package: VSSOP (US20)
- Bidirectional interface between 3.3 V and 5.0 V signals.
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 245 type.

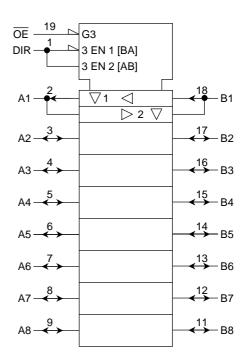
Note: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.

All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs		Outputs	Function		
ŌĒ	DIR	Odipuis	A-Bus	B-Bus	
L	L	A = B	Output	Input	
L	Н	B = A Input		Output	
Н	Х	Z	High Impedance		

X: Don't care

Z: High impedance

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Maximum Ratings

Characteristics Symbol		Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage (DIR, OE)	V _{IN}	-0.5~7.0	V
DC bus I/O voltage	V	-0.5~7.0 (Note1)	V
DC bus I/O voltage	V _{I/O}	-0.5~V _{CC} + 0.5 (Note2)	V
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note3)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65~150	°C

Note1: Output in off-state

Note2: High or low state. $I_{\mbox{\scriptsize OUT}}$ absolute maximum rating must be observed.

Note3: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vac	2.0~3.6	٧	
Supply voltage	V _{CC}	1.5~3.6 (Note4)	V	
Input voltage (DIR, OE)	V _{IN}	0~5.5	V	
Bus I/O voltage	Vuo	0~5.5 (Note5)	V	
Bus 1/O voltage	V _{I/O}	0~V _{CC} (Note6)	V	
Output current	I _{OH} /I _{OI}	±24 (Note7)	mA	
Output current	IOH/IOL	±12 (Note8)	IIIA	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note9)	ns/V	

Note4: Data retention only

Note5: Output in off-state

Note6: High or low state

Note7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note8: $V_{CC} = 2.7 \sim 3.0 \text{ V}$

Note9: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

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Electrical Characteristics

DC Characteristics (Ta = -40~85°C)

Characteristics		Symbol	Test Condition			Min	Max	Unit	
Characte	51131103	Symbol	rest Condition		V _{CC} (V)	IVIII I	IVIAX	Offic	
Input voltage	High level	V_{IH}		_	2.7~3.6	2.0	_	V	
input voitage	Low level	V _{IL}		_	2.7~3.6	_	0.8	V	
				I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_		
	High level	VoH	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	V	
				I _{OH} = -18 mA	3.0	2.4	_		
Output voltage				I _{OH} = -24 mA	3.0	2.2	_		
	, ,			$I_{OL} = 100 \mu A$	2.7~3.6	_	0.2		
Low level	V	Maria Maria and Maria	I _{OL} = 12 mA	2.7	_	0.4			
	Low level	V _{OL}	VOL	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55		
Input leakage current		I _{IN}	V _{IN} = 0~5.5 V		2.7~3.6	_	±5.0	μΑ	
3-state output off-state current		l _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0 \sim 5.5 \text{ V}$		2.7~3.6	_	±5.0	μА	
Power off leakage	ge current	l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μА	
Quiescent supply current			V _{IN} = V _{CC} or GND		2.7~3.6	_	10.0		
		I _{CC}	V _{IN} /V _{OUT} = 3.6~5.5 V		2.7~3.6	_	±10.0	μΑ	
Increase in I _{CC} per input		Δl _{CC}	V _{IH} = V _{CC} - 0.6 V 2.7~3.6		_	500			

AC Characteristics ($Ta = -40 \sim 85$ °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
Tropagation delay time	t _{pHL}	rigule 1, rigule 2	3.3 ± 0.3	1.5	7.0	
Output enable time	t _{pZL}	Figure 4 Figure 2	2.7	_	9.5	ns
Output enable time	t _{pZH}	Figure 1, Figure 3	3.3 ± 0.3	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7		8.5	ns
Output disable time	t _{pHZ}	rigure 1, rigure 3	3.3 ± 0.3	1.5	7.5	115
Output to output skew	t _{osLH}	(Note10)	2.7		_	ns
Output to output skew	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	110

Note10: This parameter is guaranteed by design.

 $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, Input: $t_r = t_f = 2.5 \text{ ns}, C_L = 50 \text{ pF}, R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic VOL	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic VOL	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

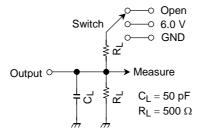
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	DIR, OE	3.3	7	pF
Bus input capacitance	C _{I/O}	A _n , B _n	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note11	3.3	25	pF

Note11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit



Paramenter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

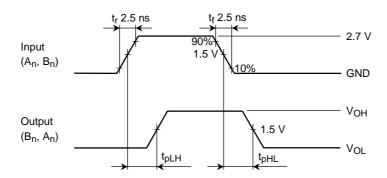
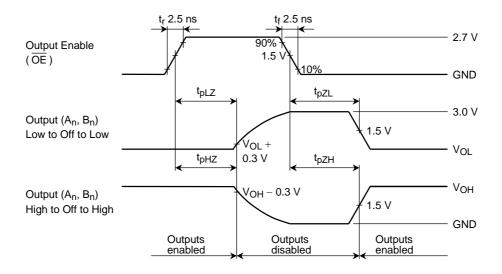
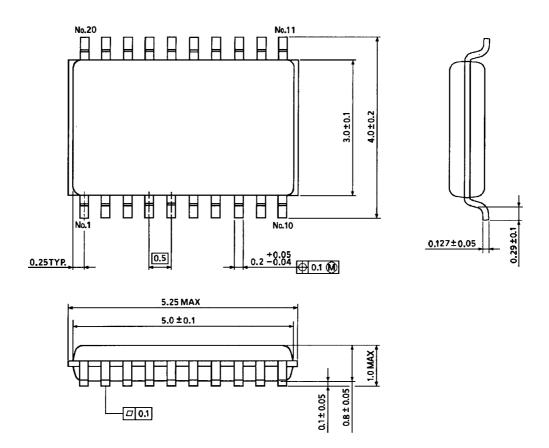


Figure 2 t_{pLH} , t_{pHL}



 $\label{eq:figure 3} \quad t_{pLZ},\,t_{pHZ},\,t_{pZL},\,t_{pZH}$

Package Dimensions



Weight: 0.03 g (typ.)

2001-09-12

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